## NSN 5962-01-106-4664

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View Online at https://aerobasegroup.com/nsn/5962-01-106-4664

view Online at https://aeiobasegioup.com/hsi//390/	2-01-100-4004
Body Length:	
0.810 inches	
Body Width:	
0.298 inches	
Body Height:	
0.165 inches	
Maximum Power Dissipation Rating:	
1.0 watts	
Operating Tempurature Range:	
+0.0/+70.0 degrees celsius	
Storage Tempurature Range:	
-55.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and monolithic and positive out	puts and edge triggered and w/enable and w/storage and w/strobe
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
N-type metal oxide-semiconductor logic	
Input Circuit Pattern:	
11 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
20.0 volts power source	
Time Rating Per Chacteristic:	
50.00 nanoseconds propagation delay time, low to	b high level output and 50.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Ram	
Memory Capacity:	
Unknown	
Test Data Document:	
05869-725000-959 drawing (this is the basic gover	ning drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other	document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:	
16 printed circuit	

16 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

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